

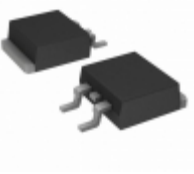


	<p>IRFBC20SPBF</p>
	<p>Hersteller-Teilenummer: IRFBC20SPBF</p> <p>Hersteller / Marke: Electro-Films (EFI) / Vishay</p> <p>Teil der Beschreibung: MOSFET N-CH 600V 2.2A D2PAK</p> <p>Datenblätter:  IRFBC20SPBF.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 6348 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	IRFBC20SPBF
Hersteller	Electro-Films (EFI) / Vishay
Beschreibung	MOSFET N-CH 600V 2.2A D2PAK
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs ,
Teilstatus	6348 pcs Stock
Hersteller Standard Vorlaufzeit	18 Weeks
detaillierte Beschreibung	N-Channel 600V 2.2A (Tc) 3.1W (Ta), 50W (Tc)
Serie	-
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-263-3, D ² Pak (2 Leads + Tab), TO-263AB
Supplier Device-Gehäuse	D2PAK
Verlustleistung (max)	3.1W (Ta), 50W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	600V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	2.2A (Tc)
Rds On (Max) @ Id, Vgs	4.4 Ohm @ 1.3A, 10V
VGS (th) (Max) @ Id	4V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	18nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	350pF @ 25V
Antriebsspannung (Max Rds On, Min Rds On)	10V
Vgs (Max)	±20V
Verpackung	Tube
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)
Andere Namen	*IRFBC20SPBF

IRFBC20SPBF ist neu im Original. Suche IRFBC20SPBF Datenblätter, PDF, Inventar bei Y-IC.com Online. Bestellen Sie IRFBC20SPBF Electro-Films (EFI) / Vishay mit Garantie und Vertrauen. Anfrage IRFBC20SPBF: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>IRFBC20STRLPBF Electro-Films (EFI) / Vishay MOSFET N-CH 600V 2.2A D2PAK</p>	 <p>IRFBC20PBF Electro-Films (EFI) / Vishay MOSFET N-CH 600V 2.2A TO-220AB</p>	 <p>IRFBC20S Vishay / Siliconix MOSFET N-CH 600V 2.2A D2PAK</p>	 <p>IRFBC20SPBF Vishay / Siliconix MOSFET N-CH 600V 2.2A D2PAK</p>
 <p>IRFBC20S Electro-Films (EFI) / Vishay MOSFET N-CH 600V 2.2A D2PAK</p>	 <p>IRFBC20PBF Vishay / Siliconix MOSFET N-CH 600V 2.2A TO-220AB</p>	 <p>IRFBC20LPBF Vishay / Siliconix MOSFET N-CH 600V 2.2A TO-262</p>	 <p>IRFBC20STRL Electro-Films (EFI) / Vishay MOSFET N-CH 600V 2.2A D2PAK</p>

heiße Teile

Mehr

 IRFB7N60C3PBF	 IRFB812PBF	 IRFB812TRPBF	 IRFB9N30A	 IRFB9N30A
 IRFB9N30APBF	 IRFB9N30APBF	 IRFB9N60A	 IRFB9N60A	 IRFB9N60APBF
 IRFB9N60APBF	 IRFB9N65	 IRFB9N65A	 IRFB9N65A	 IRFB9N65APBF
 IRFB9N65APBF	 IRFBA1404P	 IRFBA1404PPBF	 IRFBA1405P	 IRFBA22N50A
 IRFBC20-030	 IRFBC20LPBF	 IRFBC20LPBF	 IRFBC20PBF	 IRFBC20PBF
 IRFBC20SPBF	 IRFBC20STRL	 IRFBC20STRL	 IRFBC20STRLPBF	 IRFBC20STRLPBF
 IRFBC20STRR	 IRFBC20STRR	 IRFBC30ALPBF	 IRFBC30ALPBF	 IRFBC30AS
 IRFBC30AS	 IRFBC30ASPBF	 IRFBC30ASPBF	 IRFBC30ASTRL	 IRFBC30ASTRL
 IRFBC30ASTRR	 IRFBC30ASTRR	 IRFBC30ASTRRPBF	 IRFBC30ASTRRPBF	 IRFBC30LPBF
 IRFBC30LPBF	 IRFBC30LTRR	 IRFBC30PBF	 IRFBC30PBF	 IRFBC30S

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